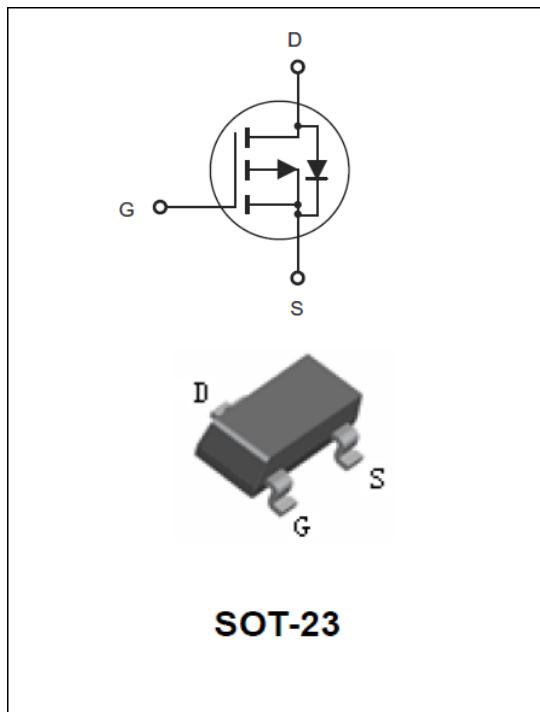


P-Channel Enhancement Mode Field Effect Transistor



Feature

- $V_{DS}=-20V, ID=-3.4A$
- $R_{DS(ON)}<64m\Omega @ V_{GS}=-4.5V$
- $R_{DS(ON)}<89m\Omega @ V_{GS}=-2.5V$
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level1
- High density cell design for low $R_{DS(ON)}$
- High Speed switching
- Rugged and reliable
- SOT-23 Package

Application

- Battery protection
- Load switch
- Power management

■ Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source Voltage	-20	V
V_{GS}	Gate-source Voltage	± 10	V
I_D	Drain Current	-3.4	A
P_D	Total Power Dissipation	1	W
R_{thJA}	Thermal Resistance From Junction To Ambient	125	°C/W
T_J	Operation Junction Temperature	-55~+150	°C
T_{STG}	Storage Temperature	-55~+150	°C

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL2301C	F2		3000	30000	120000	7" reel



YJL2301C

■ Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS}= \pm 10V, V_{DS}=0V$			± 100	nA
Gate threshold voltage*	$V_{GS(th)}$	$V_{DS}= V_{GS}, I_D=-250\mu A$	-0.4	-0.7	-1.0	V
Drain-source on-resistance*	$R_{DS(ON)}$	$V_{GS} = -4.5V, I_D=-3.4A$		49	64	$m\Omega$
		$V_{GS} = -2.5V, I_D=-3.0A$		59	89	
Forward Transconductance	g_{FS}	$V_{DS} = -5V, I_D=-3.4A$	5			s
Dynamic Characteristics **						
Input Capacitance	C_{iss}	VDS=-10V,VGS=0V,f=1MHZ		478		pF
Output Capacitance	C_{oss}			81		
Reverse Transfer Capacitance	C_{rss}			52		
Switching Characteristics**						
Turn-on delay time	$t_{d(on)}$	$V_{DD}=-10V, V_{GS}=-4.5V, RL=2.8\Omega, I_D=-1A, R_{GEN}=6\Omega$		12		ns
Turn-on rise time	t_r			54		
Turn-off delay time	$t_{d(off)}$			15		
Turn-off Fall time	t_f			9		
Total Gate Charge	Q_g	$V_{DS}=-10V, I_D=-3.4A, V_{GS}=-4.5V$		4.3		nC
Gate-Source Charge	Q_{gs}			0.8		
Gate-Drain Charge	Q_{gd}			1.1		
Source-Drain Diode characteristics						
Drain-Source Diode Forward Current	I_s				-3.4	A
Diode Forward voltage	V_{SD}	$V_{GS}=0V, I_s=-3.4A$		-0.8	-1.2	V

Notes:

*Pulse Test: Pulse Width $\leqslant 300\mu A$, Duty Cycle $\leqslant 2\%$.

**These parameters have no way to verify.

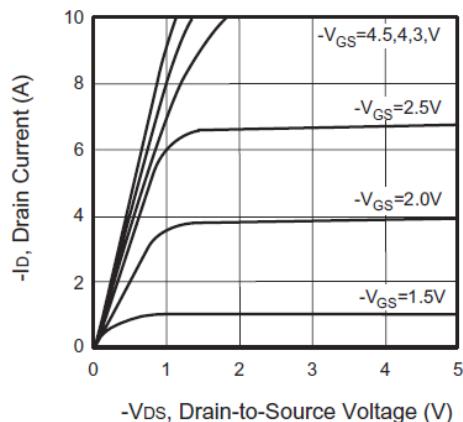
**■ Characteristics (Typical)**

Figure 1. Output Characteristics

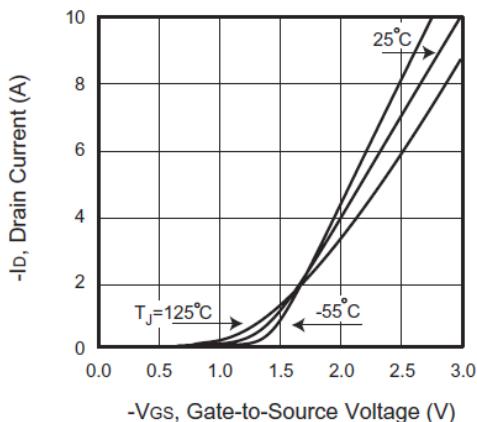


Figure 2. Transfer Characteristics

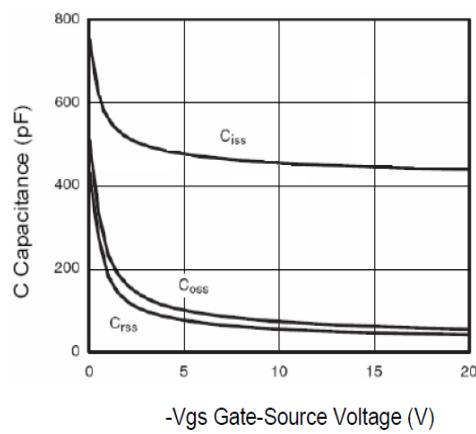


Figure 3. Capacitance

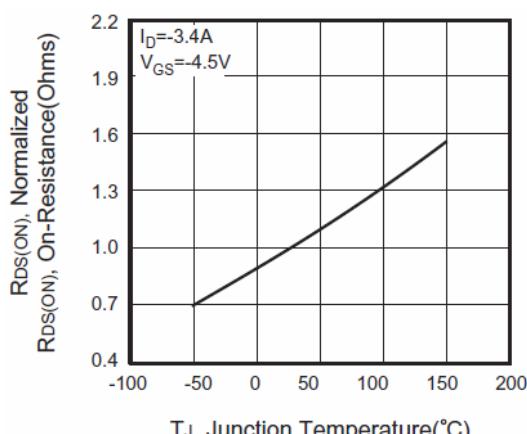


Figure 4. On-Resistance Variation with Temperature

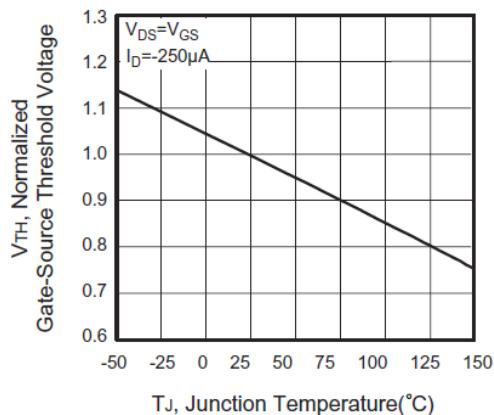


Figure 5. Gate Threshold Variation with Temperature

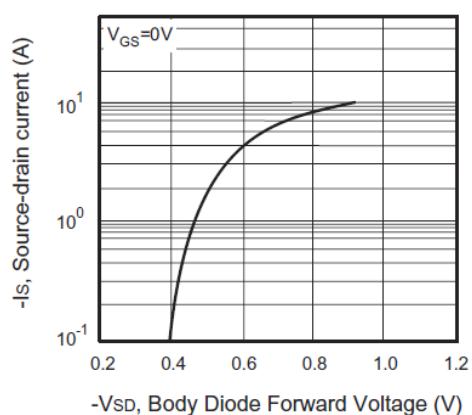
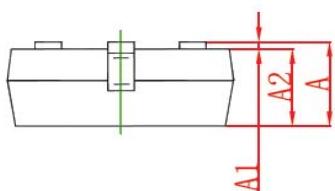
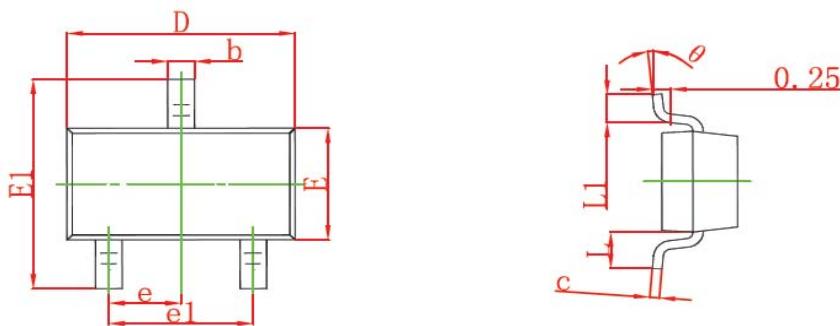
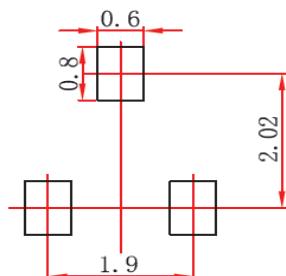


Figure 6. Body Diode Forward Voltage Variation with Source Current

**■ SOT-23 Package Outline Dimensions**

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

■ SOT-23 Suggested Pad Layout**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.



Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <http://www.21yangjie.com>, or consult your nearest Yangjie's sales office for further assistance.